

IFX20001

Low Dropout Voltage Regulator

IFX20001MBV33
IFX20001MBV50

Data Sheet

Rev. 1.1, 2013-01-08

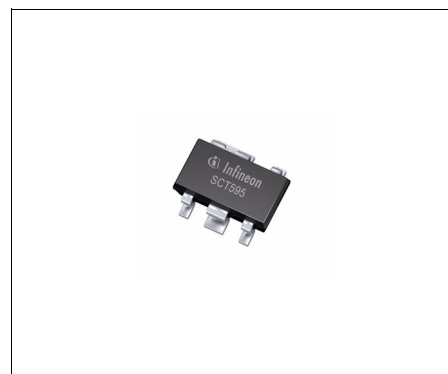
Standard Power



1 Overview

Features

- Two output voltage versions: 3.3 V, 5.0 V
- Low drop voltage ≤ 300 mV over the full temperature range
- Output current: 30 mA
- Inhibit function
- Low quiescent current
- Input voltage up to 45 V
- Wide temperature range: $-40^{\circ}\text{C} \leq T_j \leq 125^{\circ}\text{C}$
- Output protected against short circuit
- Over temperature protection
- Reverse polarity protection
- Very small and thermally enhanced package
- Green Product (RoHS compliant)



PG-SCT595-5

Applications

- Manufacturing Automation
- Appliances
- Network Routers

The **IFX20001** is not qualified and manufactured according to the requirements of Infineon Technologies with regards to automotive and/or transportation applications. For automotive applications please refer to the Infineon TLx (TLE, TLS, TLF.....) voltage regulator products.

Description

The **IFX20001** is a monolithic integrated low drop voltage regulator in a very small SMD package PG-SCT595-5. It is designed to supply various loads (e.g. micro controllers, sensors, or as standby supply, etc) under severe conditions. Therefore the device is equipped with additional protection functions against overload, short circuit and reverse polarity. In case of an over temperature condition the regulator is automatically turned off by the integrated thermal protection circuit.

Input voltages up to 40 V are regulated to $V_{Q,nom} = 3.3$ V (V33 version) or 5.0 V (V50 version). The output is able to drive a load of 30 mA while it regulates the output voltage within a 4% accuracy. To save energy the device can be switched to stand-by mode via an inhibit input which causes the current consumption to drop below 5 μA .

Type	Package	Marking
IFX20001MBV33	PG-SCT595-5	V3
IFX20001MBV50	PG-SCT595-5	V5

2 Block Diagram

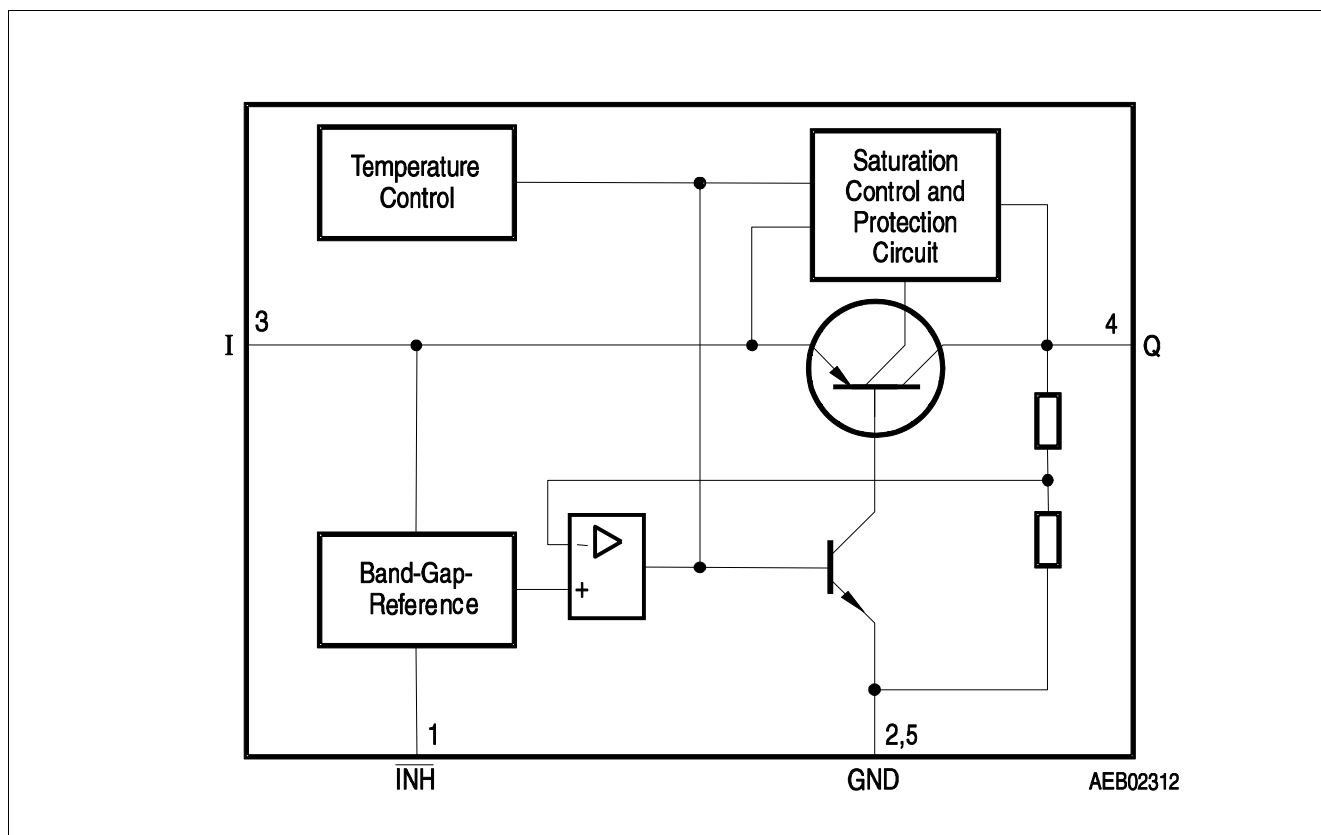


Figure 1 Block Diagram

3 Pin Configuration

3.1 Pin Assignment

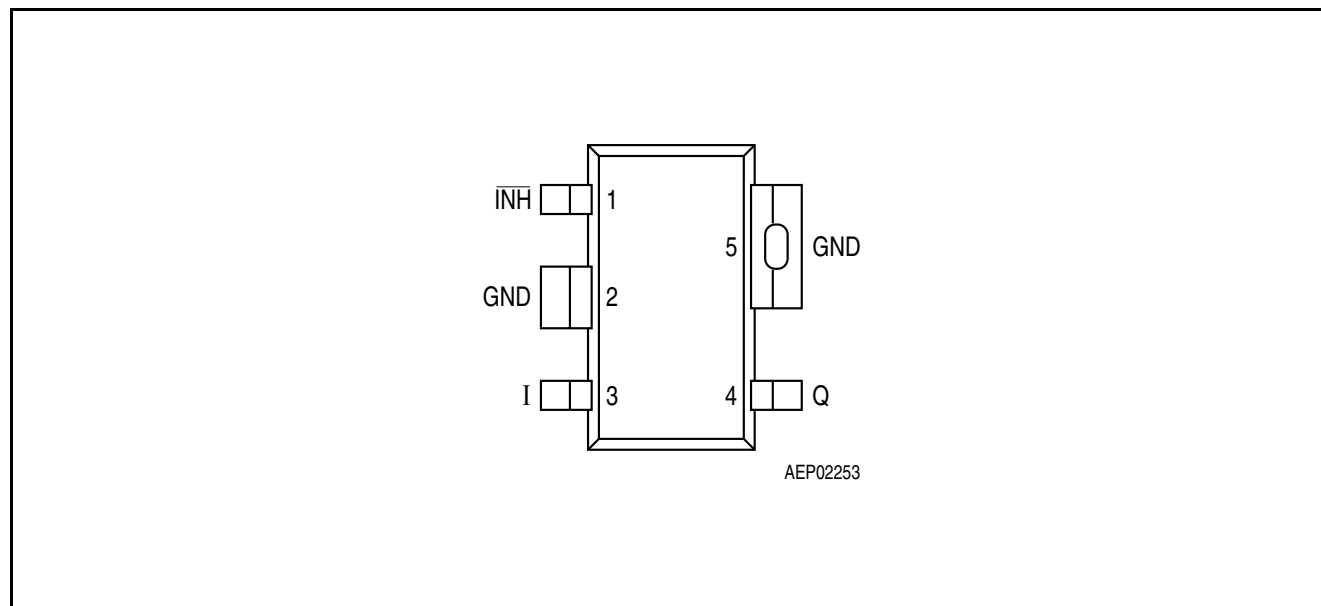


Figure 2 Pin Configuration (top view)

3.2 Pin Definitions and Functions

Table 1 Pin Definitions and Functions Fixed Output Voltage Versions

Pin No.	Symbol	Function
1	INH	Inhibit input ; high level to turn on the IC
2	GND	Ground ; connected to pin 5
3	I	Input voltage
4	Q	Output voltage ; must be blocked with a capacitor $C_Q \geq 3.3 \mu F^{1) 2)}$
5	GND	Ground ; connected to pin 2

1) Output capacitor requirements for IFX20001MBV33: $C_Q \geq 3.3 \mu F$, $2.5 \Omega \leq ESR \leq 6 \Omega$

2) Output capacitor requirements for IFX20001MBV50: $C_Q \geq 3.3 \mu F$, $2.5 \Omega \leq ESR \leq 8 \Omega$

4 General Product Characteristics

4.1 Absolute Maximum Ratings

Absolute Maximum Ratings¹⁾

$T_j = -40\text{ °C to }150\text{ °C}$; all voltages with respect to ground, (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values		Unit	Test Condition
			Min.	Max.		
Input I						
4.1.1	Voltage	V_I	-42	45	V	–
Output Q						
4.1.2	Voltage	V_Q	-6	30	V	–
Inhibit						
4.1.3	Voltage	V_{INH}	-42	45	V	
4.1.4	Current	I_{INH}	-500	*	μA	* internally limited
4.1.5	Current	I_{INH}	-5	5	mA	-0.3 V < V_I < 45 V; t_p < 1 ms
Temperature						
4.1.6	Junction temperature	T_j	-40	150	°C	–
4.1.7	Storage temperature	T_{stg}	-50	150	°C	–

1) not subject to production test, specified by design

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as “outside” normal operating range. Protection functions are not designed for continuous repetitive operation.

4.2 Functional Range

Pos.	Parameter	Symbol	Limit Values		Unit	Remarks
			Min.	Max.		
4.2.1	Input voltage	V_I	4.0	45	V	IFX20001MBV33
4.2.2	Input Voltage	V_I	5.5	45	V	IFX20001MBV50
4.2.3	Inhibit Voltage	V_{INH}	-0.3	40	V	
4.2.4	Junction temperature	T_j	-40	125	°C	—

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.

4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Typ.	Max.		
4.3.5	Junction to Ambient	R_{thJA}	—	81	—	K/W	2s2p board ¹⁾
4.3.1			—	217	—	K/W	Footprint only ²⁾
4.3.2			—	117	—	K/W	300 mm ² PCB heatsink area ²⁾
4.3.3			—	103	—	K/W	600 mm ² PCB heatsink area ²⁾
4.3.4	Junction to Soldering Point	R_{thJSP}	—	30	—	K/W	Pins 2, 5 fixed to T_A

- 1) Specified R_{thJA} value is according to JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The product (chip+package) was simulated on a 76.2 x 114.3 x 1.5 mm board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable a thermal via array under the package contacted the first inner copper layer.
- 2) Package mounted on PCB FR4; 80 x 80 x 1.5 mm; 35 µm Cu, 5 µm Sn; horizontal position; zero airflow. Not subject to production test; specified by design.

5 Electrical Characteristics

5.1 Electrical Characteristics Voltage Regulator

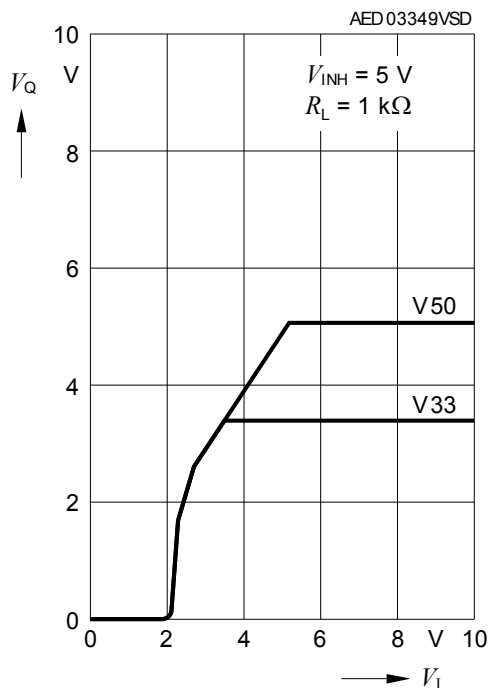
Table 2 Electrical Characteristics
 $V_I = 13.5 \text{ V}$; $V_{INH} > +2.5 \text{ V}$; $-40 \text{ }^\circ\text{C} < T_j < 125 \text{ }^\circ\text{C}$; unless otherwise specified

Parameter	Symbol	Limit Values			Unit	Test Condition
		Min.	Typ.	Max.		
Output voltage V33 version	V_Q	3.17	3.30	3.43	V	$1 \text{ mA} < I_Q < 30 \text{ mA}$ $V_I = 13.5 \text{ V}$
		3.17	3.30	3.43	V	$I_Q = 10 \text{ mA}$ $4.3 \text{ V} < V_I < 40 \text{ V}$
Output voltage V50 version	V_Q	4.80	5.00	5.20	V	$1 \text{ mA} < I_Q < 30 \text{ mA}$ $V_I = 13.5 \text{ V}$
		4.80	5.00	5.20	V	$I_Q = 10 \text{ mA}$ $6 \text{ V} < V_I < 40 \text{ V}$
Output current limitation	I_Q	30	–	–	mA	¹⁾
Drop voltage	V_{dr}	–	0.25	0.30	V	$I_Q = 20 \text{ mA}^{1)}$
Output capacitor	C_Q	3.3	–	–	μF	IFX20001MBV33: $2.5 \Omega \leq \text{ESR} \leq 6 \Omega$ at 10 kHz
	C_Q	3.3	–	–	μF	IFX20001MBV50: $2.5 \Omega \leq \text{ESR} \leq 8 \Omega$ at 10 kHz
Current consumption $I_q = I_I - I_Q$	I_q	–	2	4.5	mA	$I_Q < 30 \text{ mA}$
Current consumption $I_q = I_I - I_Q$	I_q	–	110	170	μA	$I_Q < 1 \text{ mA}$; $T_j < 85 \text{ }^\circ\text{C}$
Quiescent current (stand-by) $I_q = I_I - I_Q$	I_q	–	0	1	μA	$V_{INH} = 0.4 \text{ V}$; $T_j < 85 \text{ }^\circ\text{C}$
Quiescent current (stand-by) $I_q = I_I - I_Q$	I_q	–	0	5	μA	$V_{INH} = 0.4 \text{ V}$
Load regulation	ΔV_Q	–	10	20	mV	$1 \text{ mA} < I_Q < 25 \text{ mA}$; $T_j = 25 \text{ }^\circ\text{C}$
Line regulation	ΔV_Q	–	5	20	mV	$V_I = (V_{Q,nom} + 0.5 \text{ V})$ to 36 V $I_Q = 5 \text{ mA}$; $T_j = 25 \text{ }^\circ\text{C}$
Power Supply Ripple Rejection	$PSRR$	–	60	–	dB	$f_r = 100 \text{ Hz}$; $V_r = 0.5 \text{ V}_{pp}$
Inhibit Input						
Inhibit, Turn-on voltage	$V_{INH, high}$	–	–	2.2	V	$V_Q > 0.95 V_{Q,nom}$
Inhibit, Turn-off voltage	$V_{INH, low}$	0.4	–	–	V	$V_Q > 0.1 \text{ V}$
H-input current	$I_{INH, high}$	–	8	12	μA	$V_{INH} = 5 \text{ V}$
L-input current	$I_{INH, low}$	-2	–	2	μA	$V_{INH} = 0 \text{ V}$

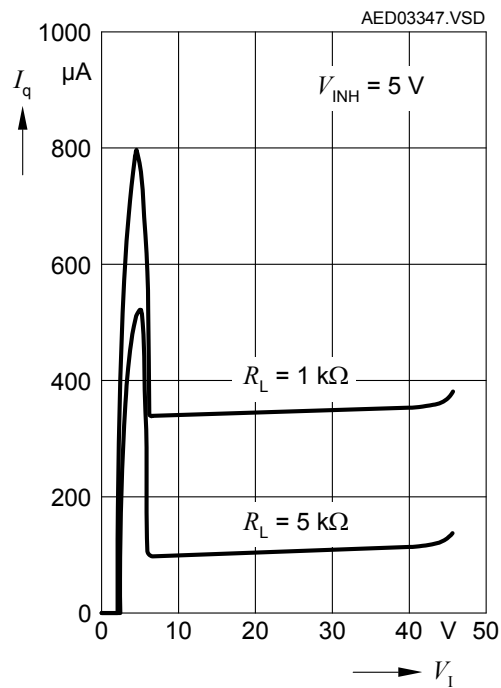
¹⁾ Measured when the output voltage V_Q has dropped 100 mV from the nominal value.

5.2 Typical Performance Characteristics Voltage Regulator

Output Voltage V_Q versus
Input Voltage V_I



Current Consumption I_q versus
Input Voltage V_I



6 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

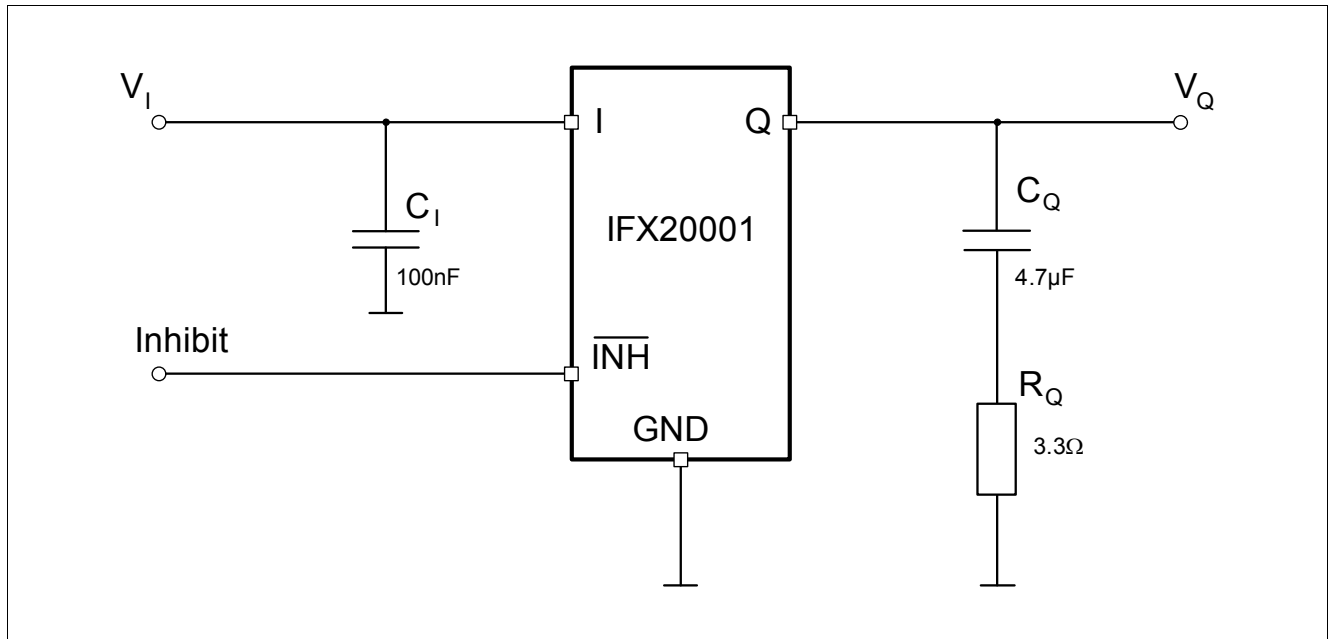


Figure 3 Application Diagram

Application Information

The output voltage of the IFX20001 is divided and compared to an internal reference of 2.5 V typical. A regulation loop controls the output to achieve a stabilized output voltage.

Figure 3 shows a typical application circuit. In order to maintain the stability of the control loop the IFX20001 output requires an output capacitor C_Q of at least 3.3 μF with a minimum required ESR of 2.5 Ω and a maximum allowed ESR of 6 Ω for the IFX20001MBV33 and 8 Ω for the IFX20001MBV50. It is recommended to use for C_Q a suitable tantalum capacitor or a multilayer ceramic capacitor with a sufficiently dimensioned series resistor in order to cover the required ESR range over the full operating temperature range from -40 $^{\circ}\text{C}$ to 125 $^{\circ}\text{C}$.¹⁾

At the input of the regulator a capacitor is required for compensating line influences. A resistor of approximately 1 Ω in series with the input capacitor (C_I) can dampen oscillations that could occur due to the input line inductance and the input capacitor.

1) For usage of ceramic capacitors without applying an additional series resistor at the output please refer to the **IFX20002** which is a corresponding voltage regulator series specially designed for the usage of low-ESR output capacitors (< 2 Ω).

7 Package Outlines

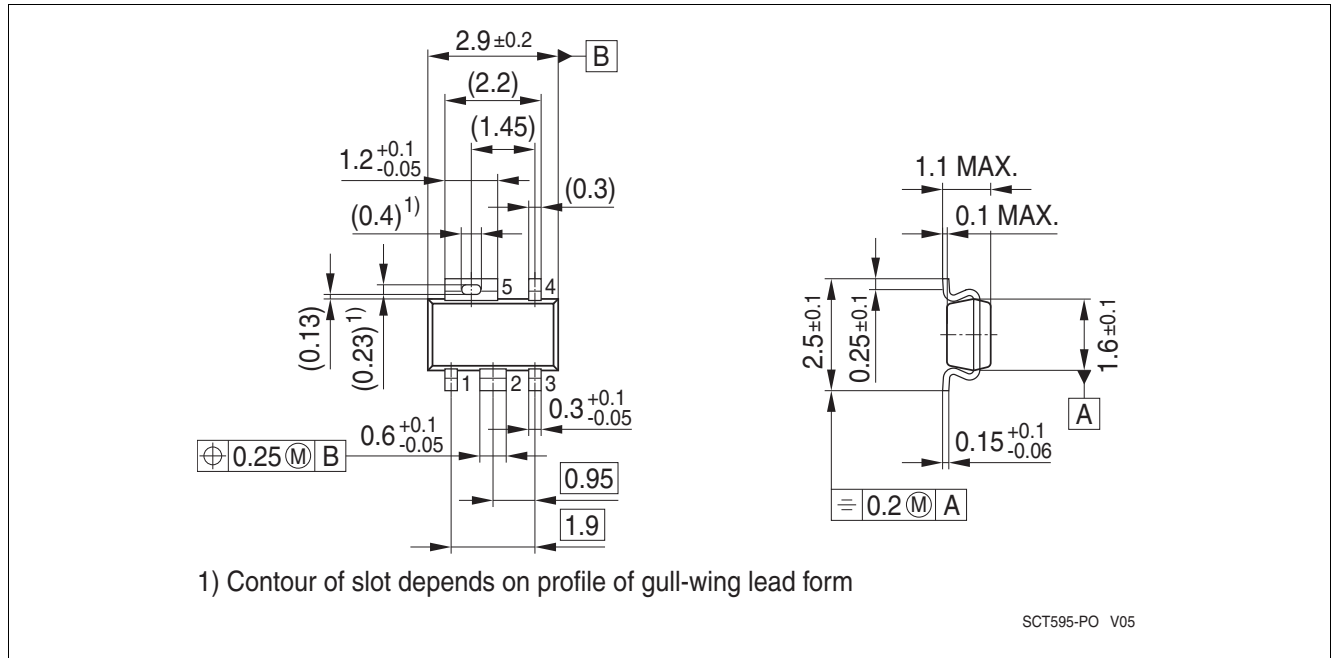


Figure 4 PG-SCT595-5

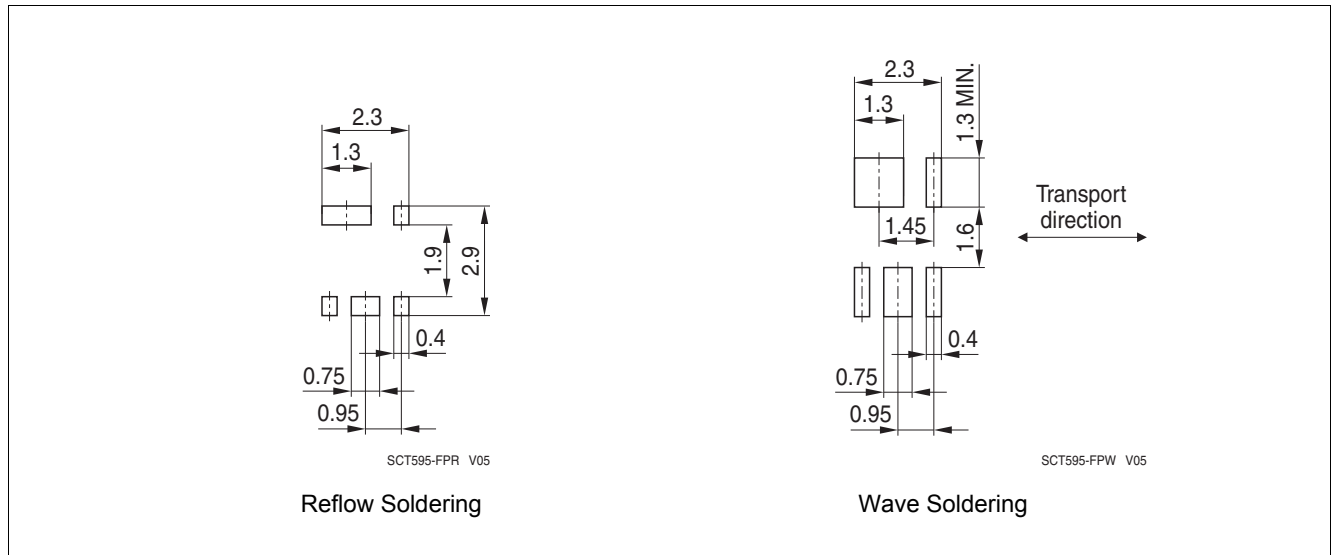


Figure 5 Footprint PG-SCT595-5

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e. Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on packages, please visit our website:

<http://www.infineon.com/packages>.

Dimensions in mm

8 Revision History

Revision	Date	Changes
1.1	2013-01-08	Corrected ESR requirements for output capacitor (chapt. 3.2, table1 / chapt. 5.1, table2 / chapt. 6, "Application Information"). remarks/footnotes with respect to ESR added (chapt.6). Updated application diagram (fig.3). Updated (improved) limits of parameters current consumption, line regulation and load regulation in electrical characteristics (chapt. 5.1, table 2). Test condition for current consumption adapted. Updated minimum limit for absolute maximum ratings of V_Q (chapt. 4.1). Further editorial changes.
1.02	2010-05-20	Editorial change (fig.3)
1.01	2009-09-10	Coverpage changed Overview page: Inserted reference statement to TLE/TLF series.
1.0	2009-04-28	Initial Release

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